

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Michelle D. Griglione

Serial No.: 10/598,213

Filed: August 21, 2006

For: A BIPOLAR JUNCTION TRANSISTOR HAVING A HIGH
GERMANIUM CONCENTRATION IN A SILICON-
GERMANIUM LAYER AND A METHOD FOR FORMING THE
BIPOLAR JUNCTION TRANSISTOR

Group No.: 2893

Examiner: Benjamin T. Liu

Confirmation No.: 1211

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed
with United States Patent and trademark Office on:

August 31, 2009 (Date)

Elizabeth Schumacher
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/
(Signature of the person signing the certificate)

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed May 29, 2009, please reconsider the above-
identified application for the following reasons: